

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE6080D uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

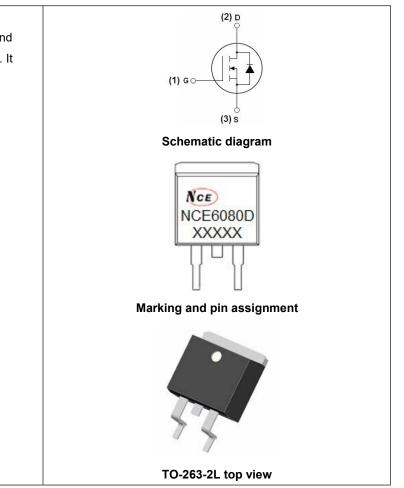
- V_{DS} =60V,I_D =80A
- R_{DS(ON)} <6.9mΩ @ V_{GS}=10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAs
- Excellent package for good heat dissipation

Application

- PWM
- Load Switching

100% UIS TESTED!

100% ΔVds TESTED!



Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|----------|----------------|-----------|------------|----------|
| NCE6080D | NCE6080D | TO-263-2L | - | - | - |

Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

| U , | 5 (5 | | | | |
|--|----------------------------------|------------|------|--|--|
| Parameter | Symbol | Limit | Unit | | |
| Drain-Source Voltage | Vds | 60 | V | | |
| Gate-Source Voltage | Vgs | ±20 | V | | |
| Drain Current-Continuous | Ι _D | 80 | A | | |
| Drain Current-Continuous(Tc=100 ℃) | l₀(100℃) | 56.5 | A | | |
| Pulsed Drain Current | I _{DM} | 320 | A | | |
| Maximum Power Dissipation | PD | 110 | W | | |
| Derating factor | | 0.73 | W/°C | | |
| Single pulse avalanche energy (Note 5) | Eas | 390 | mJ | | |
| Operating Junction and Storage Temperature Range | T _J ,T _{STG} | -55 To 175 | °C | | |
| Thermal Characteristic | | | | | |
| Thermal Resistance, Junction-to-Case ^(Note 2) | R _{θJC} | 1.36 | °C/W | | |
| | | | | | |



Electrical Characteristics (Tc=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|--|-----|------|------|------|
| Off Characteristics | · | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 60 | - | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =60V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} =±20V,V _{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | · | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_D=250\mu A$ | 2 | 2.8 | 4 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =10V, I _D =20A | - | 6 | 6.9 | mΩ |
| Forward Transconductance | g fs | V _{DS} =5V,I _D =20A | 20 | - | - | S |
| Dynamic Characteristics (Note4) | · | | | | | |
| Input Capacitance | Clss | | - | 4000 | - | PF |
| Output Capacitance | Coss | V_{DS} =30V, V_{GS} =0V, | - | 290 | - | PF |
| Reverse Transfer Capacitance | Crss | F=1.0MHz | - | 210 | - | PF |
| Switching Characteristics (Note 4) | · | | • | | | |
| Turn-on Delay Time | t _{d(on)} | | - | 8.5 | - | nS |
| Turn-on Rise Time | tr | V_{DD} =30V,RL=1 Ω | - | 7 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =10V, R_{G} =3 Ω | - | 40 | - | nS |
| Turn-Off Fall Time | t _f | | - | 15 | - | nS |
| Total Gate Charge | Qg | N/ 001/11 000 | - | 90 | | nC |
| Gate-Source Charge | Q _{gs} | $V_{DS}=30V, I_{D}=20A,$ | - | 9 | | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} =10V | - | 18 | | nC |
| Drain-Source Diode Characteristics | I | | | | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =20A | - | | 1.2 | V |
| Diode Forward Current (Note 2) | ls | | - | - | 80 | Α |
| Reverse Recovery Time | trr | TJ = 25°C, IF = 20A | - | 32 | - | nS |
| Reverse Recovery Charge | Qrr | di/dt = 100A/µs ^(Note3) | - | 45 | - | nC |
| Forward Turn-On Time | t _{on} | Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD) | | | | |

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

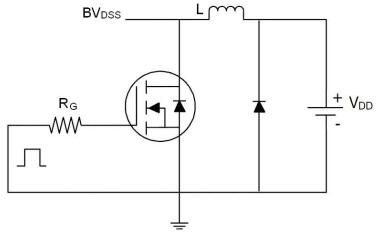
2. Surface Mounted on FR4 Board, $t \le 10$ sec.

- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. E_{AS} condition : Tj=25 $^\circ \! \mathrm{C}$,V_{DD}=30V,V_G=10V,L=0.5mH,Rg=25\Omega

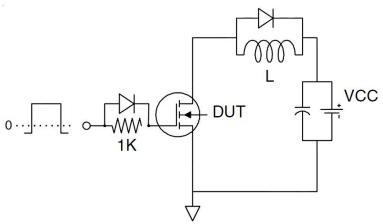


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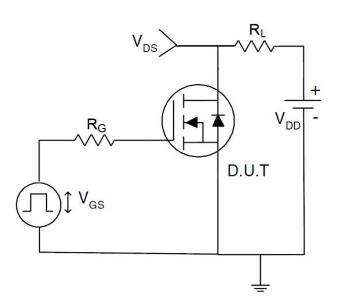
Test circuit 1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



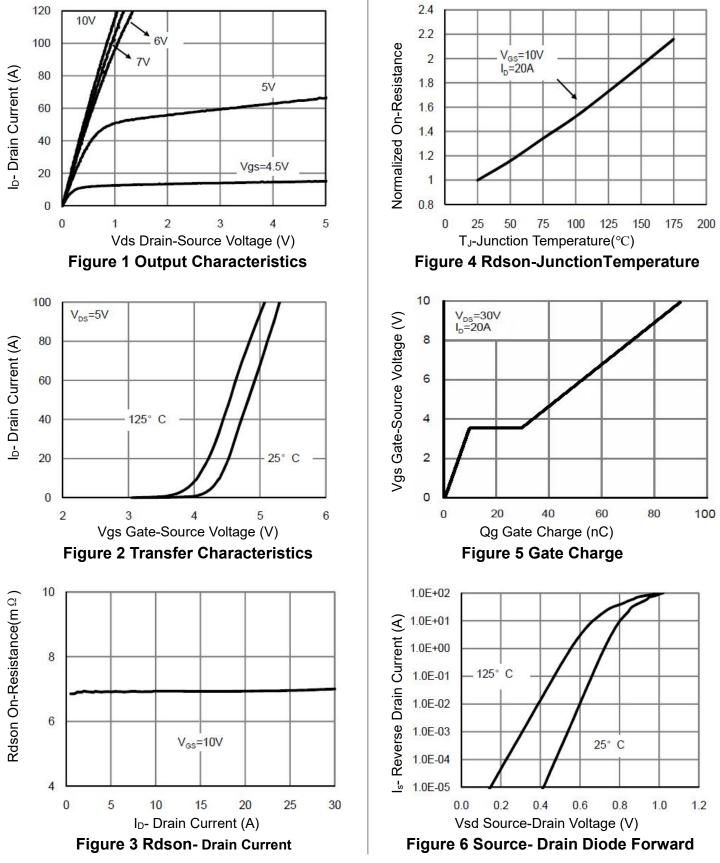
3) Switch Time Test Circuit





NCE6080D

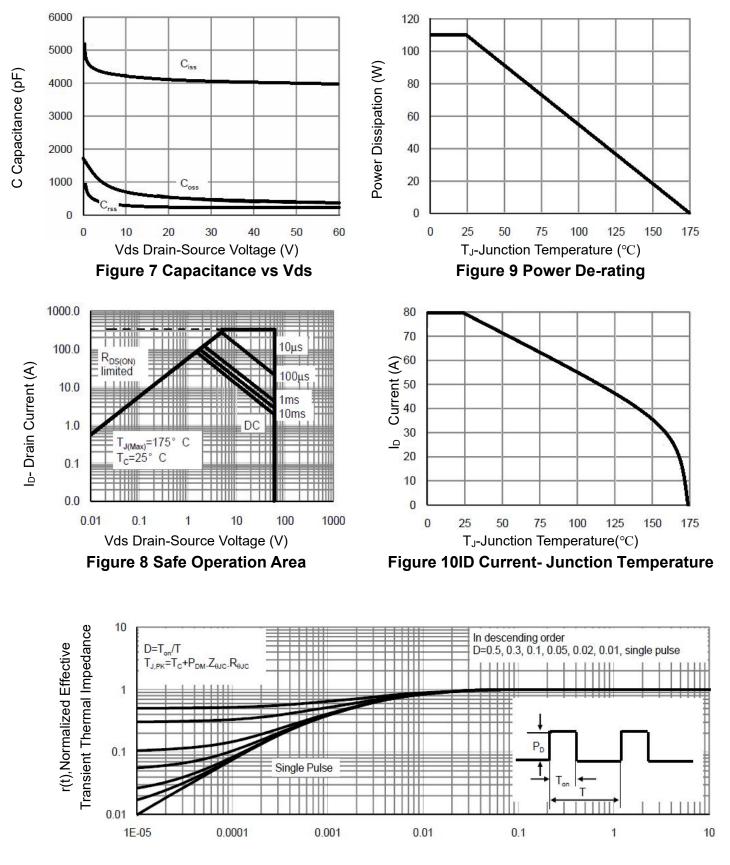






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NCE6080D



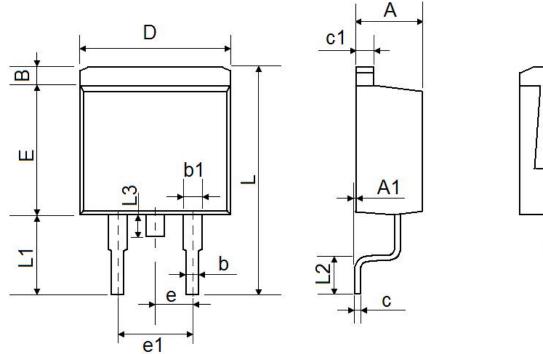
Square Wave Pluse Duration(sec)

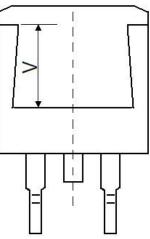
Figure 11 Normalized Maximum Transient Thermal Impedance



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TO-263-2L Package Information





| Symbol | Dimensions | In Millimeters | Dimensions In Inches | | |
|--------|------------|----------------|----------------------|-------|--|
| | Min. | Max. | Min. | Max. | |
| А | 4.470 | 4.670 | 0.176 | 0.184 | |
| A1 | 0.000 | 0.150 | 0.000 | 0.006 | |
| В | 1.170 | 1.370 | 0.046 | 0.054 | |
| b | 0.710 | 0.910 | 0.028 | 0.036 | |
| b1 | 1.170 | 1.370 | 0.046 | 0.054 | |
| С | 0.310 | 0.530 | 0.012 | 0.021 | |
| c1 | 1.170 | 1.370 | 0.046 | 0.054 | |
| D | 10.010 | 10.310 | 0.394 | 0.406 | |
| E | 8.500 | 8.900 | 0.335 | 0.350 | |
| е | 2.540 TYP. | | 0.100 TYP. | | |
| e1 | 4.980 | 5.180 | 0.196 | 0.204 | |
| L | 15.050 | 15.450 | 0.593 | 0.608 | |
| L1 | 5.080 | 5.480 | 0.200 | 0.216 | |
| L2 | 2.340 | 2.740 | 0.092 | 0.108 | |
| L3 | 1.300 | 1.700 | 0.051 | 0.067 | |
| V | 5.600 |) REF | 0.220 REF | | |



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